

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Vishnu K. Agarwal et al.

Examiner:

Hoai V Pham

Serial No.:

10/053,300

Group Art Unit:

2814

Filed:

January 17, 2002

Docket:

303.780US1

Title:

TRANSISTOR STRUCTURE HAVING REDUCED TRANSISTOR LEAKAGE

ATTRIBUTES

INFORMATION DISCLOSURE STATEMENT

MS RCE Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

In compliance with the duty imposed by 37 C.F.R. § 1.56, and in accordance with 37 C.F.R. §§ 1.97 et. seq., the enclosed materials are brought to the attention of the Examiner for consideration in connection with the above-identified patent application. Applicants respectfully request that this Information Disclosure Statement be entered and the documents listed on the attached Form 1449 be considered by the Examiner and made of record. Pursuant to the provisions of MPEP 609, Applicants request that a copy of the 1449 form, initialed as being considered by the Examiner, be returned to the Applicants with the next official communication.

Pursuant to 37 C.F.R. §1.97(b), it is believed that no fee or statement is required with the Information Disclosure Statement.

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Pursuant to 37 C.F.R. 1.98(a)(2), Applicant believes that copies of cited U.S. Patents and Published Applications are no longer required to be provided to the Office. Notification of this change was provided in the United States Patent and Trademark Office OG Notices dated October 12, 2004. Thus, Applicant has not included copies of any US Patents or Published Applications cited with this submission. Should the Office require copies to be provided, Applicant respectfully requests that notice of such requirement be directed to Applicant's below-signed representative. Applicant acknowledges the requirement to submit copies of foreign patent documents and non-patent literature in accordance with 37 C.F.R. 1.98(a)(2).

The Examiner is invited to contact the Applicants' Representative at the below-listed telephone number if there are any questions regarding this communication.

Respectfully submitted,

VISHNU K. AGARWAL ET AL.

By their Representatives,

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A. P.O. Box 2938
Minneapolis, MN 55402

(612) 349-9587

Date 15 June 15 By

Timothy B Clise

Ting Kolonik

Signature

Name

PTO/SB/08&(10-01)
Approved for use through 10/31/2002, OMB 651-0031
US Patent & Trademark Office: U.S. DEPARTMENT OF COMMERCE
Under the Paperwork Reduction Act of 1985, no persons are required to respond to a collection of information unless it contains a valid OMB control number. Substitute for form 1449A/PTO Complete if Known INFORMATION DISCLOSURE **Application Number** 10/053,300 **TATEMENT BY APPLICANT** January 17, 2002 Filing Date ny sheets as necessary) Agarwal, Vishnu **First Named Inventor Group Art Unit** 2814 **Examiner Name** Pham, Hoai

Attorney Docket No: 303.780US1

US PATENT DOCUMENTS				
Examiner Initial *	USP Document Number	Publication Date	Name of Patentee or Applicant of cited Document	Filing Date If Appropriate
	US-5,674,775	10/07/1997	Ho, C., et al.	02/20/1997
	US-5,811,346	09/22/1998	Sur, H., et al.	04/14/1997
	US-5,989,975	11/23/1999	Kuo, Chien-Li	12/18/1997
	US-5,998,852	12/07/1999	Berry, W., et al.	05/15/1998
	US-6,097,069	08/01/2000	Brown, J., et al.	06/22/1998
	US-6,174,786	01/16/2001	Kelley, P., et al.	11/23/1999
	US-6,287,921	09/11/2001	Chern, Y.	03/29/2000

S/N 10/053,300 PATENT

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JUN 17 2005

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EDUCED TRANSISTOR LEAKAGE

COMMUNICATION CONCERNING RELATED APPLICATION(S)

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Applicants would like to bring to the Examiner's attention the following related application(s) in the above-identified patent application:

Serial/Patent No.

Filing Date

Attorney Docket

Title

10/931513

September 1, 2004

303.780US2

TRANSISTOR STRUCTURE HAVING

REDUCED TRANSISTOR LEAKAGE

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Continuations and divisionals may be later filed on the cases listed above, or cited to the Examiner in any previous Communication Concerning Related Applications. Applicant requests that the Examiner review all continuations and divisionals of the above-listed or previously-cited patent applications before allowing the claims of the present patent application.

Respectfully submitted,

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